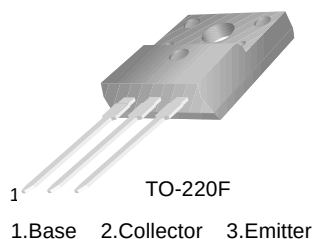


FJPF13007

High Voltage Fast-Switching NPN Power Transistor

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Mode Power Supply



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	8	A
I _{CP}	Collector Current (Pulse)	16	A
I _B	Base Current	4	A
P _C	Collector Dissipation (T _C = 25°C)	40	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10\text{mA}, I_B = 0$	400			V
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 9\text{V}, I_C = 0$			1	μA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 2\text{A}$ $V_{CE} = 5\text{V}, I_C = 5\text{A}$	8 5		60 30	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 2\text{A}, I_B = 0.4\text{A}$ $I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 2\text{A}$			1.0 2.0 3.0	V V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 2\text{A}, I_B = 0.4\text{A}$ $I_C = 5\text{A}, I_B = 1\text{A}$			1.2 1.6	V V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$	4			MHz
C_{ob}	Output Capacitance	$V_{CB} = 10\text{V}, f = 0.1\text{MHz}$		110		pF
t_{ON}	Turn On Time	$V_{CC} = 125\text{V}, I_C = 5\text{A}$			1.6	μs
t_{STG}	Storage Time	$I_{B1} = -I_{B2} = 1\text{A}$ $R_L = 25\Omega$			3.0	μs
t_F	Fall Time				0.7	μs

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$ **h_{FE} Classification**

Classification	H1	H2
h_{FE1}	15 ~ 28	26 ~ 39

Typical Performance Characteristics

Figure 1. DC Current Gain

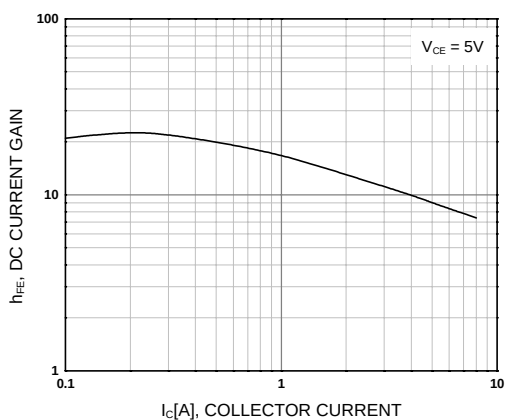


Figure 2. Saturation Voltage

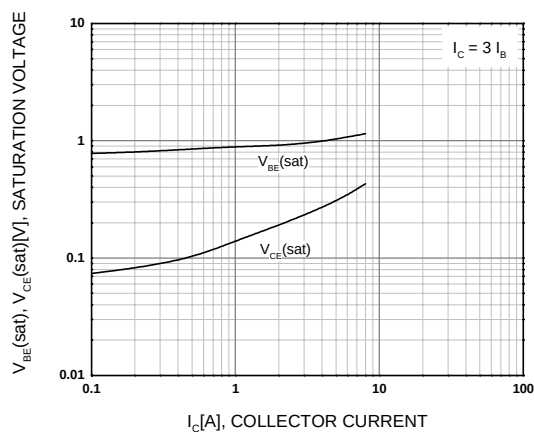


Figure 3. Collector Output Capacitance

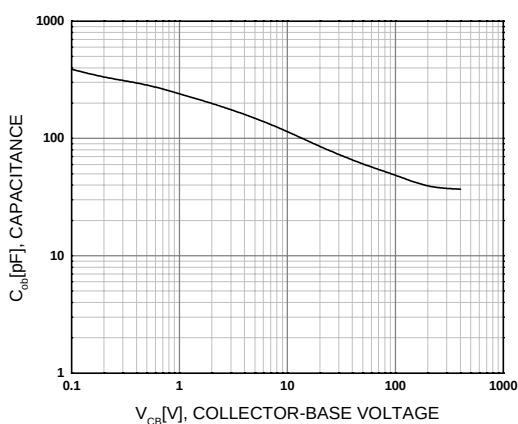


Figure 4. Turn On Time

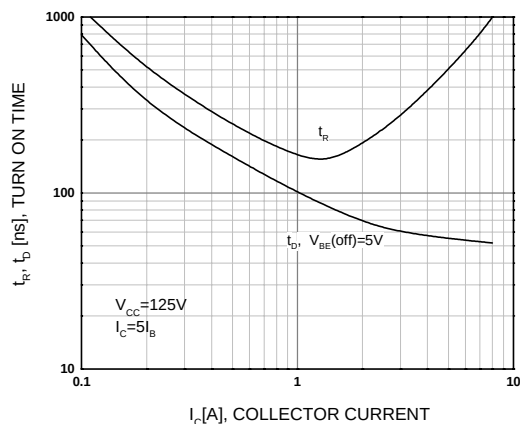


Figure 5. Turn Off Time

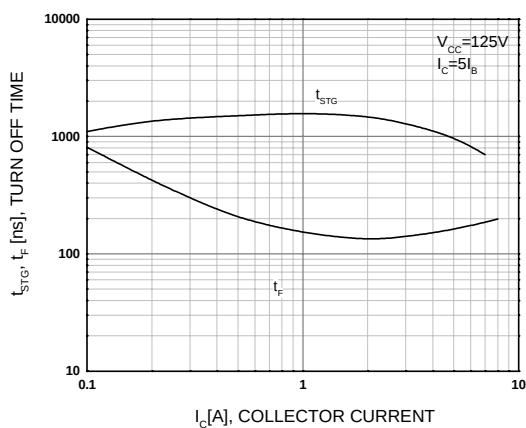
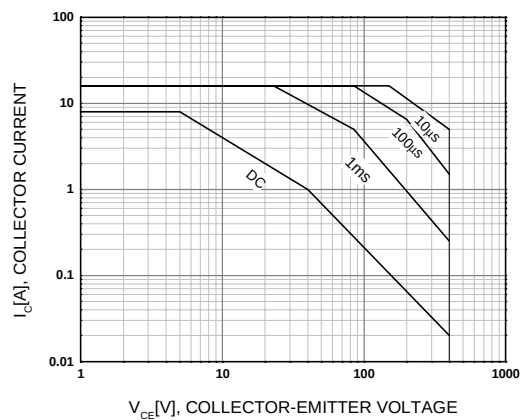


Figure 6. Forward Biased Safe Operating Area



Typical Performance Characteristics (Continued)

Figure 7. Reverse Biased Safe Operating Area

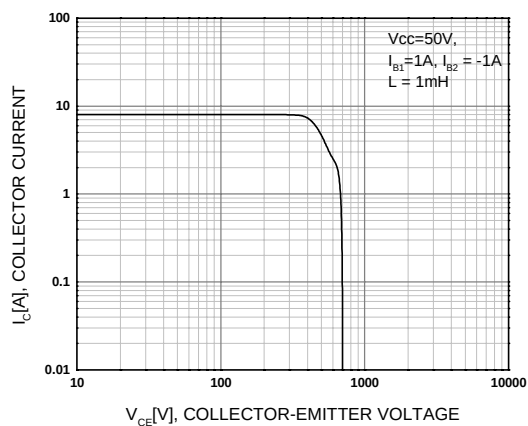
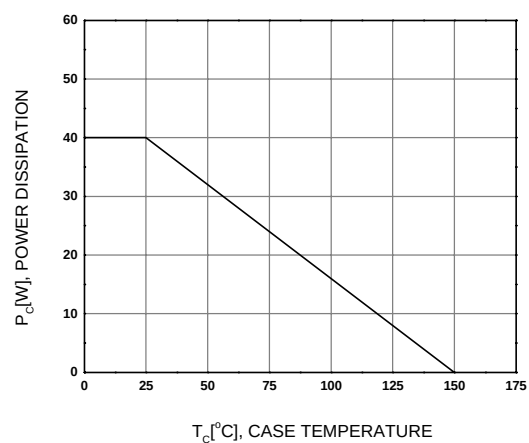
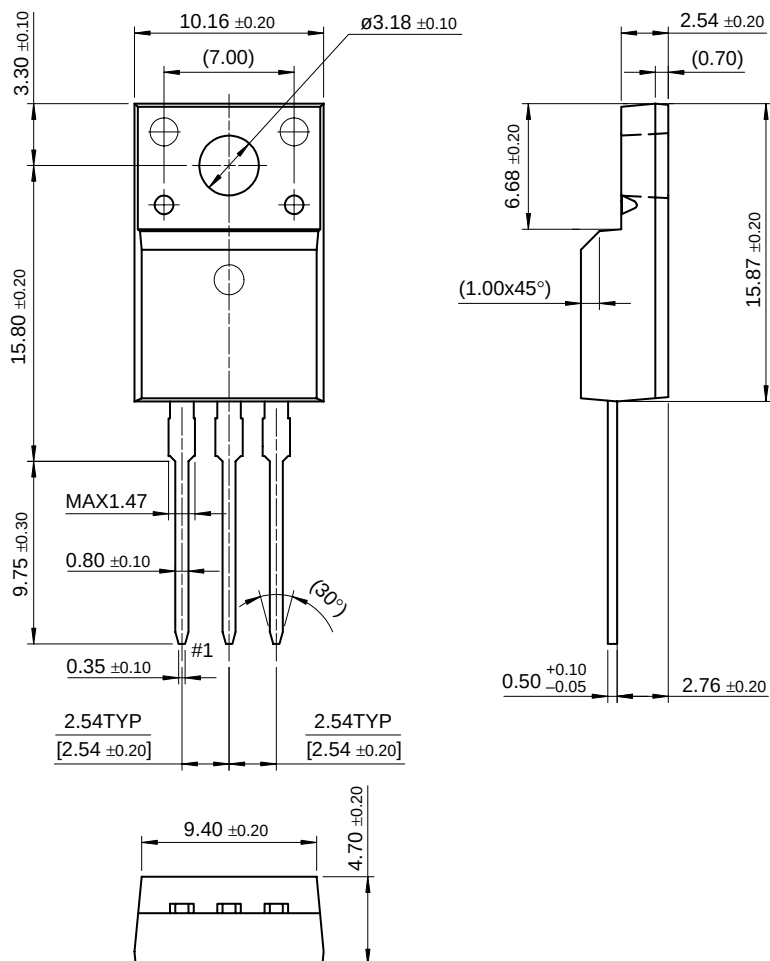


Figure 8. Power Derating



Mechanical Dimensions

TO-220F



Dimensions in Millimeters

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